Sheet 1 of 1

PTO-1449

JAN 30 2004

INFORMATION DISCLOSURE CITATION IN AN APPLICATION

(Use several sheets if necessary)

Docket Number (Optional)	Application Number
HALO-01-014B	10/697,925
Applicant: Seiki Ogura et al.	
Filing Date: 10/30/03	Group Art Unit

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
DN	4943943	7/24/90	Hayashi et al.	365	185	7/24/84
DN	5768192	6/16/98	Eitan	365	185.24	7/23/96

FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation YES	Translation NO
DN	JP1 1-229400	12/5/97	Japan	H01L	27/115		
DN	JP0 0-314355	7/8/98	Japan	H01L	27/115		

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

DN F. Masuoka et al., "A New NAND Cell for Ultra High Density 5V-Only EEPROMs," May 1988, Proc. 1988 Symp. on VLSI Tech, IV-5, pp. 33-34

EXAMINER	DATE CONSIDERED
[signature]	7/8/05

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.